
Recent developments regarding Optical MEMS and their applications

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HISTORY

Fraunhofer IPMS

1992 Fraunhofer IPMS started as branch of the Fraunhofer Institute of Microelectronic Circuits and Systems

2003 Fraunhofer Institute for Photonic Microsystems (Fraunhofer IPMS) became an independent institute in Dresden

2005 Fraunhofer Center Nanoelectronic Technologies (Fraunhofer CNT) founded as Public Private Partnership with AMD & Infineon

2007 Modernization of the institute and opening of a new MEMS clean room

2013 Fraunhofer CNT became a department of Fraunhofer IPMS as business field IPMS-CNT



IPMS building



IPMS-CNT building

Fraunhofer IPMS clean rooms



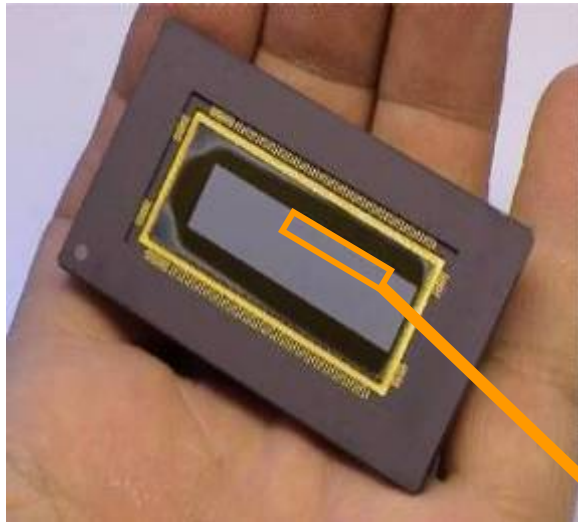
- 1500 m², class 10
 - 150 mm (6") Wafer line
 - 3 shift preparation for R&D and pilot fabrication
 - Technological parameter supervising system
 - PPS based planning and documentation
 - ISO 9001 certification
- 800 m² clean room, class 1000 & 200 m² laboratory area
 - 40 Tools for Wafer Processing, Patterning, Metrology & Analytics
 - Qualification of processes & materials on 300 mm industrial standard equipment
 - Sub-nm characterization and verification
 - Full integration into customer process flow in 28 nm technology and beyond

Fraunhofer IPMS Location in the „Silicon Saxony“

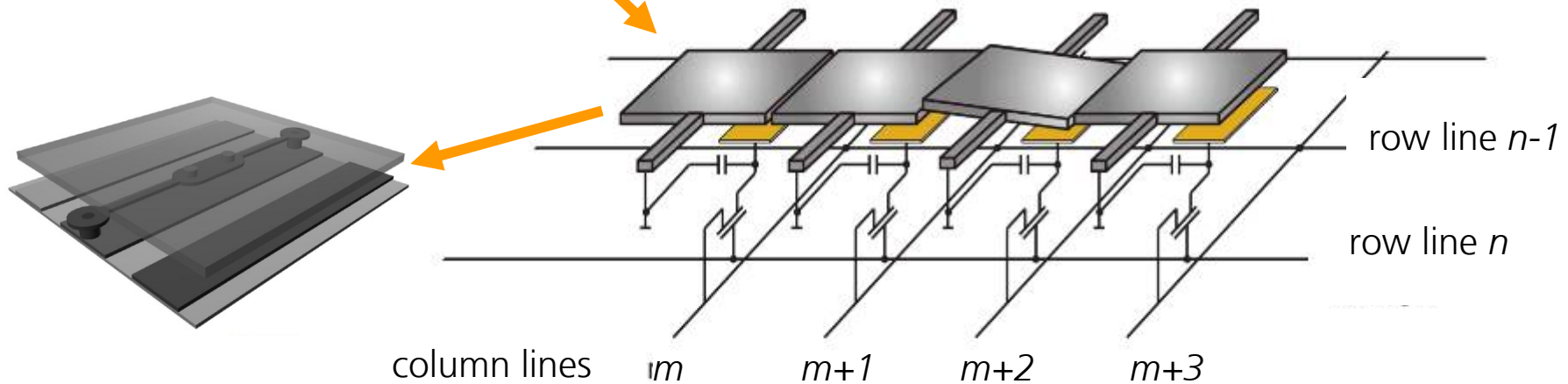
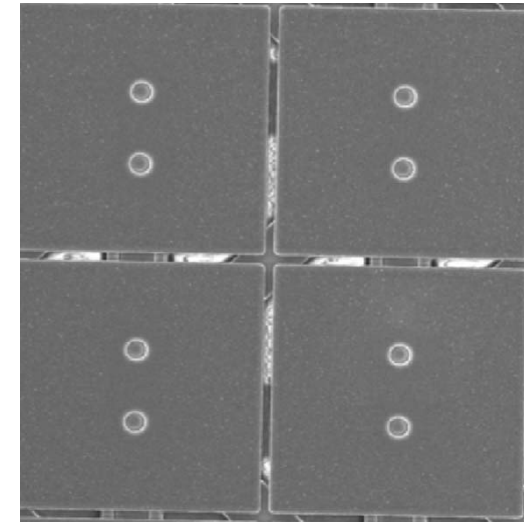


Sources: Google / Bing / Infineon / Globalfoundries

Spatial Light Modulators

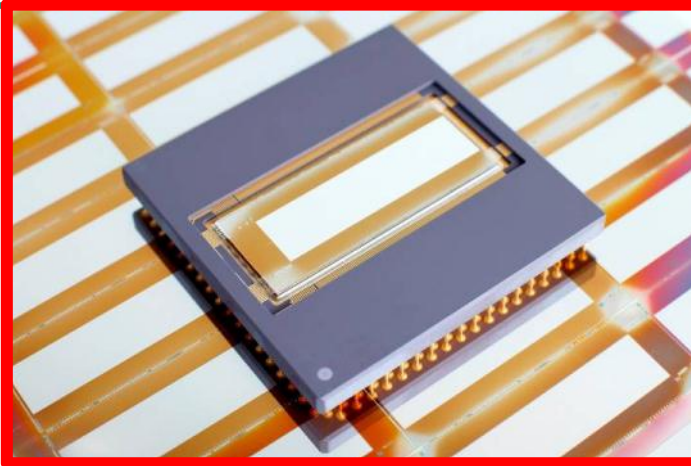


16 μm pitch
2048 x 512 pixel
(1Mega-Pixel)
2 kHz frame rate
Operating wavelength
248nm



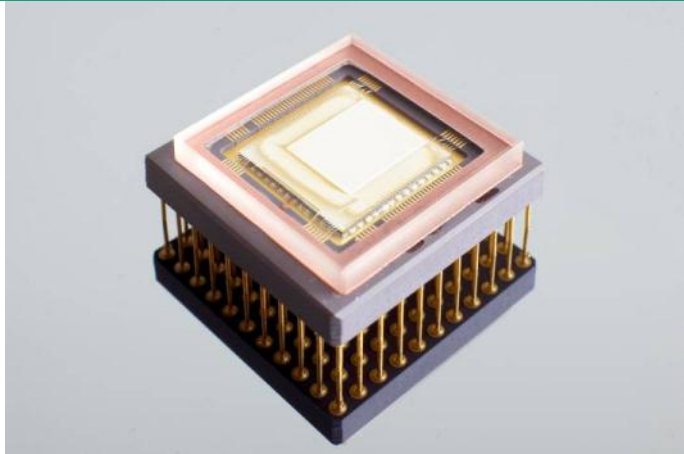
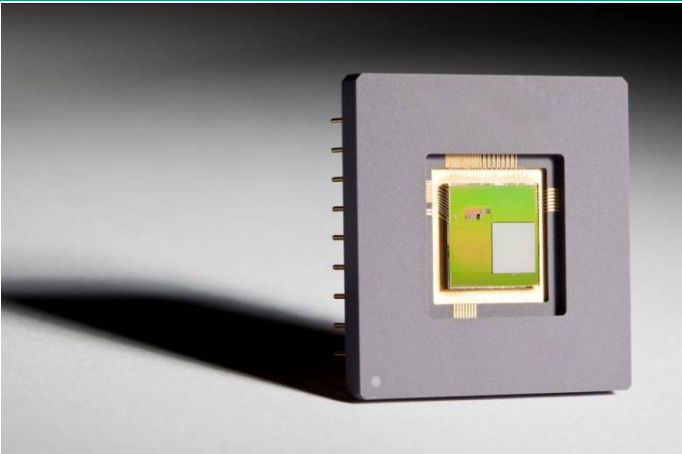
Custom-built SLM by Fraunhofer IPMS: Applications

Laser Direct Imaging



Mask Writing

Microscopy



Adaptive Optics

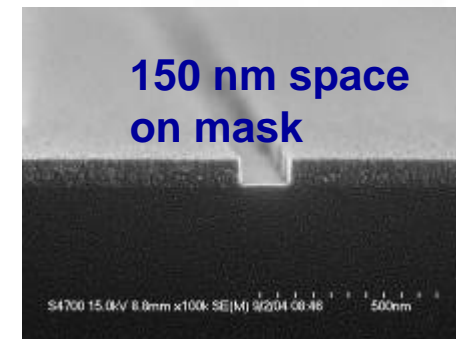
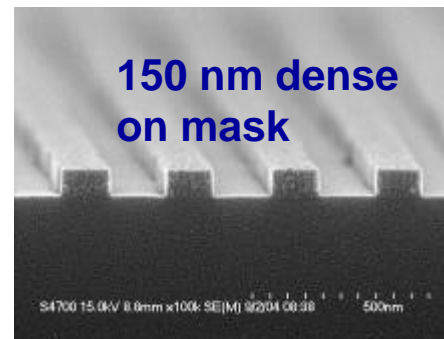
MICRONIC MYDATA's SIGMA 7700 Mask Writer

Application

- Quick turn-around and cost-effective production of reticles.
- Prints entire mask set at the 90nm technology node, and non-critical photomasks down to the 22nm node
- 3h per reticle (4-pass writing), ~1.5h (2-pass-writing)
- ideal solution for 2nd layer patterning of advanced PSM and well-suited for advanced image sensors



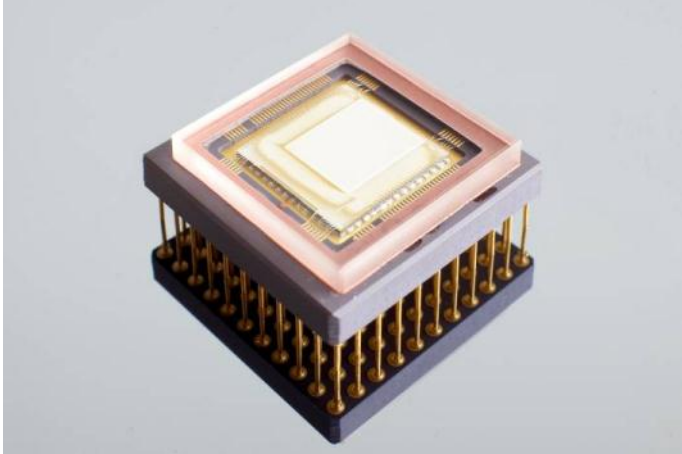
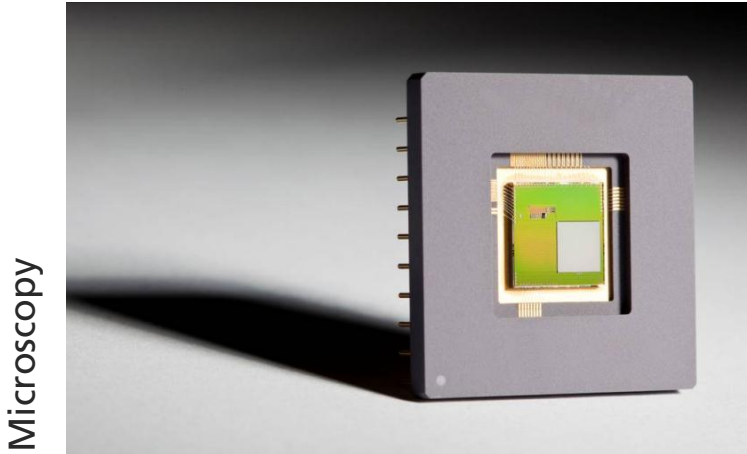
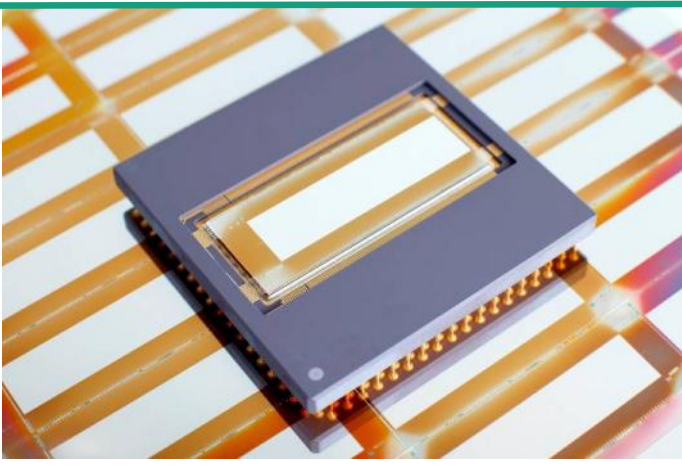
MICRONIC MYDATA



Status: Several systems in field

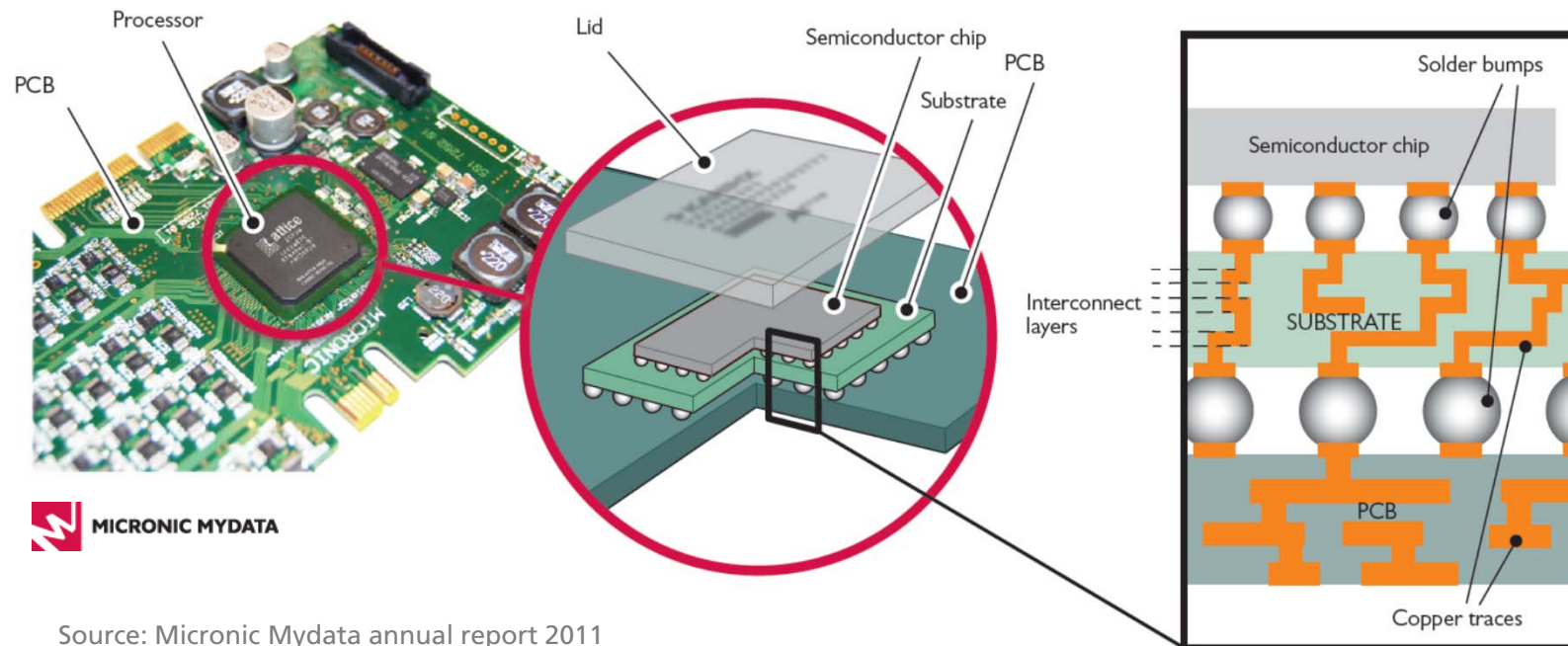
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Custom-built SLM by Fraunhofer IPMS: Applications



Introduction: Laser direct imaging in substrate industry

- In semiconductor packages, interposers and substrates interface chips to the outside world. Advanced packages require a LS resolution down to 10 μm .
- Cost-effective substrates are produced from organic (plastic film) material. They are processed in form of large panels (e.g. 51cm x 51.5cm).



Source: Micronic Mydata annual report 2011
<http://www.micronic-mydata.com>

Introduction: Laser direct imaging in substrate industry

- Micronic Mydata's new LDI5sp system accounts for shape changes: high resolution and pattern overlay without loss of productivity.
- Fraunhofer IPMS contributed spatial light modulator (SLM) to the system.

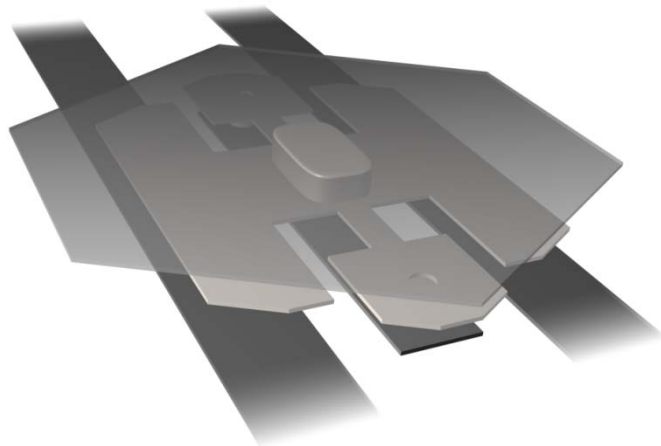
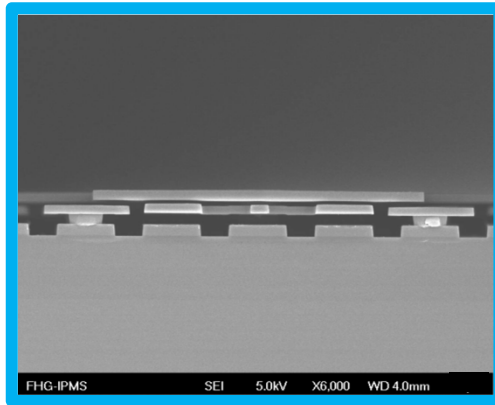


Micronic Mydatas LDI5sp exposure system

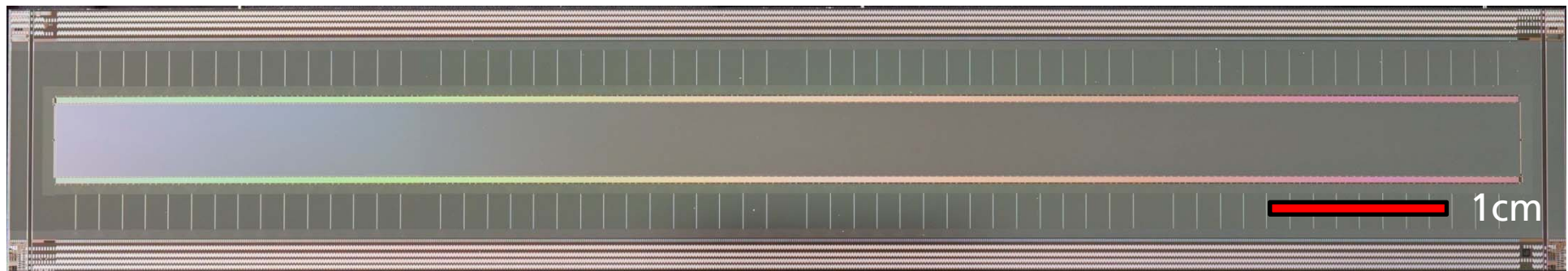


Fast one-dimensional analog SLM, 8192 Pixel

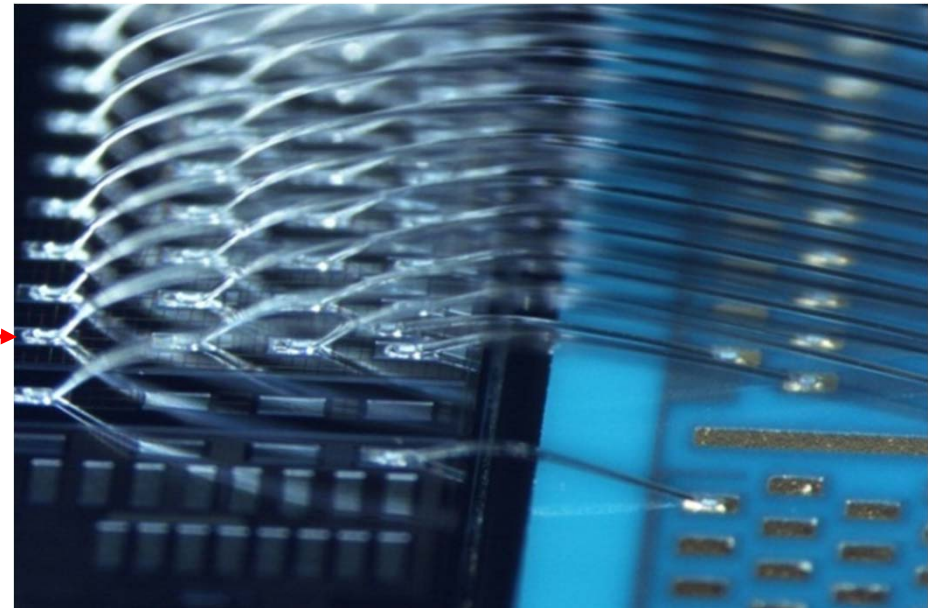
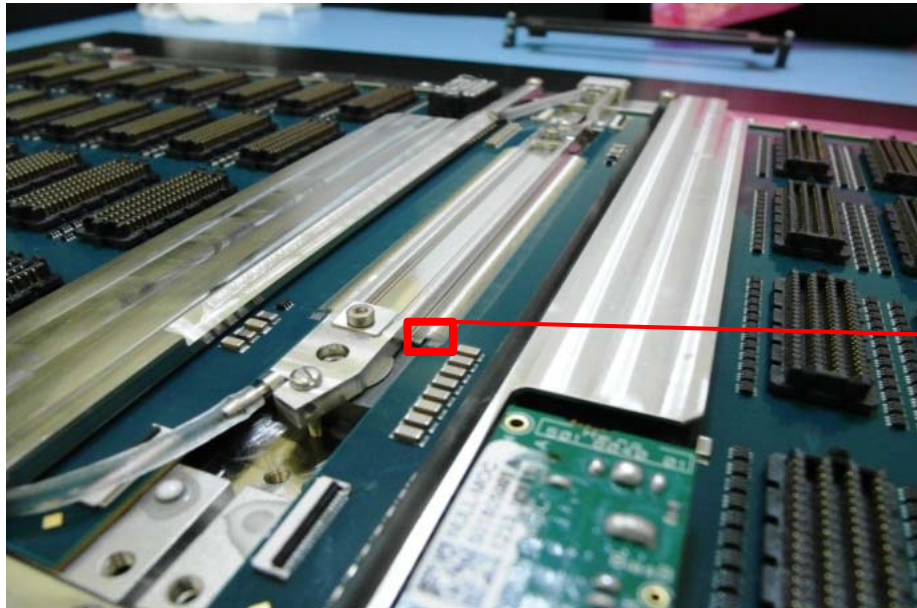
SLM features



LDI SLM Parameter	Value
Chip dimensions [mm]	15 x 88
Dimensions of pixel area [mm]	4 x 82
Fill grade of active area [%]	> 90
Number of optical pixels	8192
Mirrors per optical pixel	268
Mirror material	Al-alloy
Operating wavelength [nm]	355
Mirror reflectance at 355nm [%]	> 85
Pixel resonance frequency [MHz]	> 1.3
Achieved contrast	Up to 1000



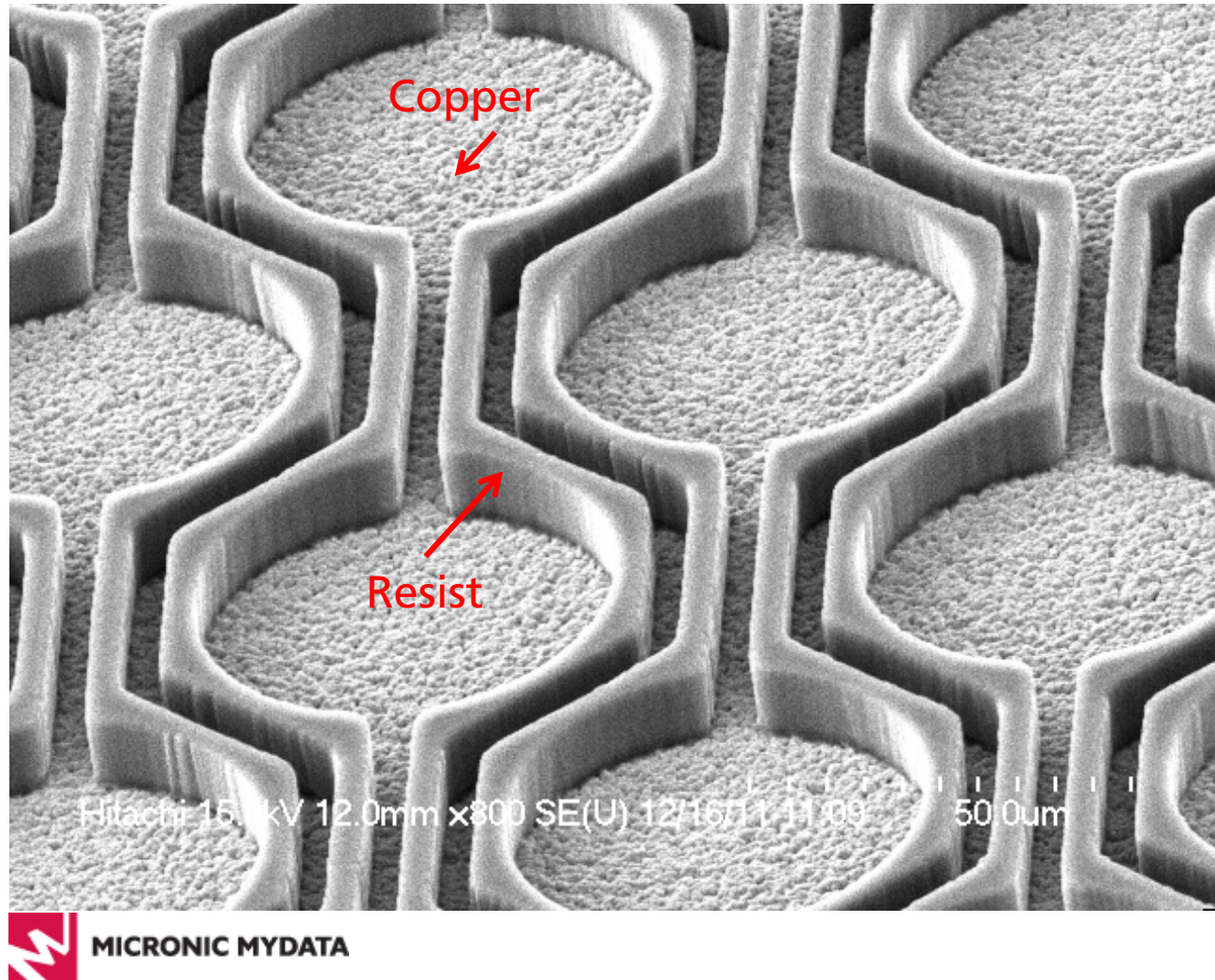
Assembly of SLM chip



- SLM electrodes are hard wired to external data path.
- This enables a high-rate parallel update of all pixels.

SLM performance in exposure system: Exposure results

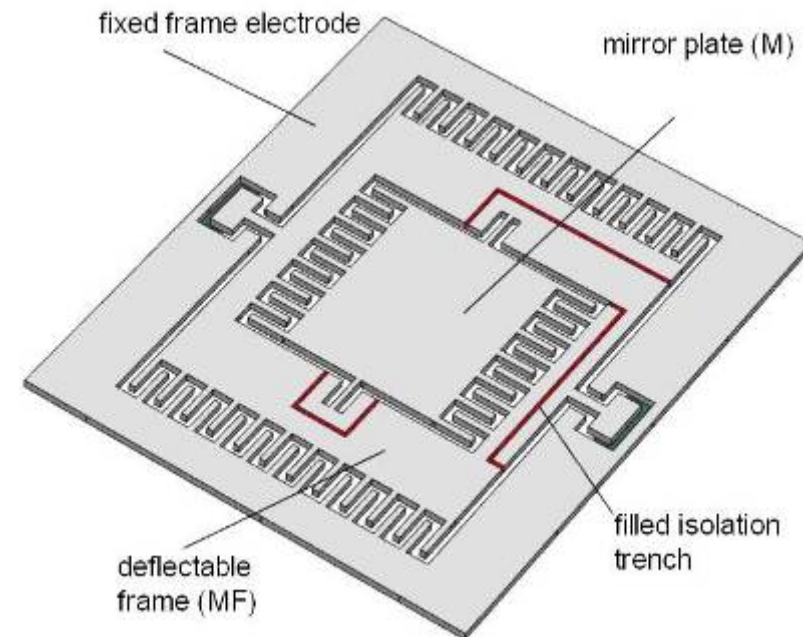
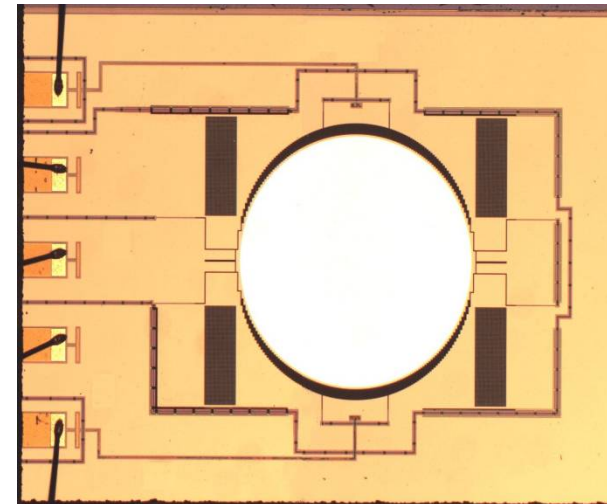
- 15 μm DFR on Cu seed layer, patterned with a micro-VIA interconnect test pattern. Minimum line/space feature size is 6 μm .



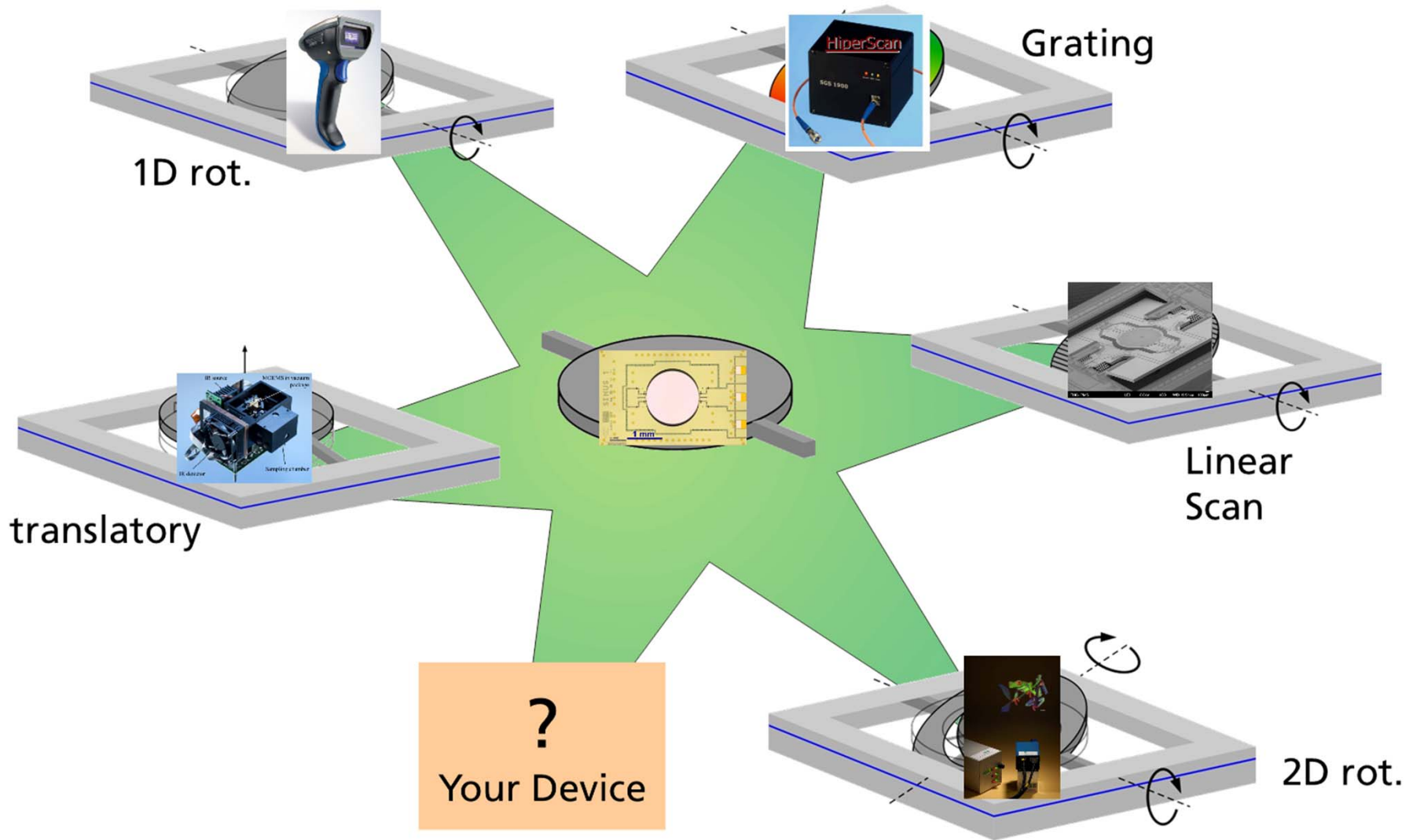
Micro Scanning Mirrors

■ Technology

- Bulk micromachining
- 1D-Scanner
- Frequency: 250 Hz
- Diameter: 1.5 mm
- Deflection angle: up to $\pm 34^\circ$
(136° optical scan range)

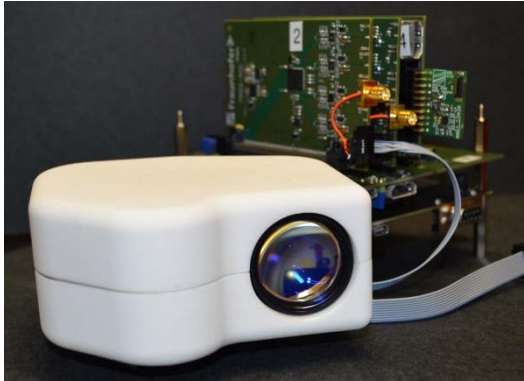
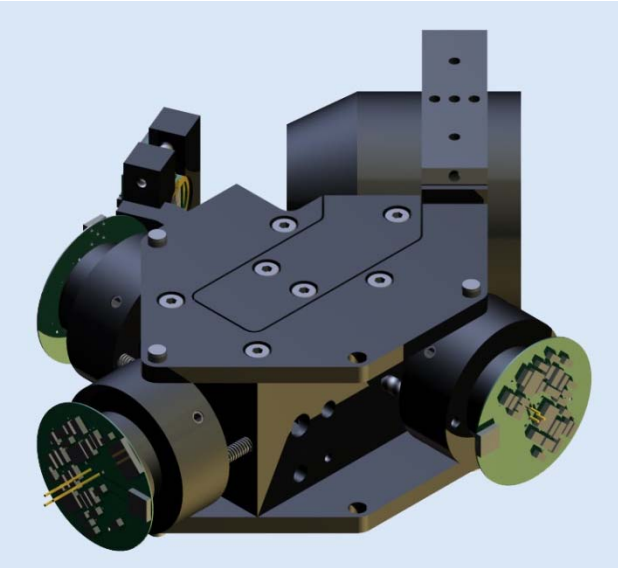


Micro Scanning Mirror Variants and Applications



Application: Biometry

MARS: Mobile Authentication by Retina Scanning



GEFÖRDERT VOM



Bundesministerium
für Bildung
und Forschung



Technologiezentrum



Fraunhofer
ISI



pitcom



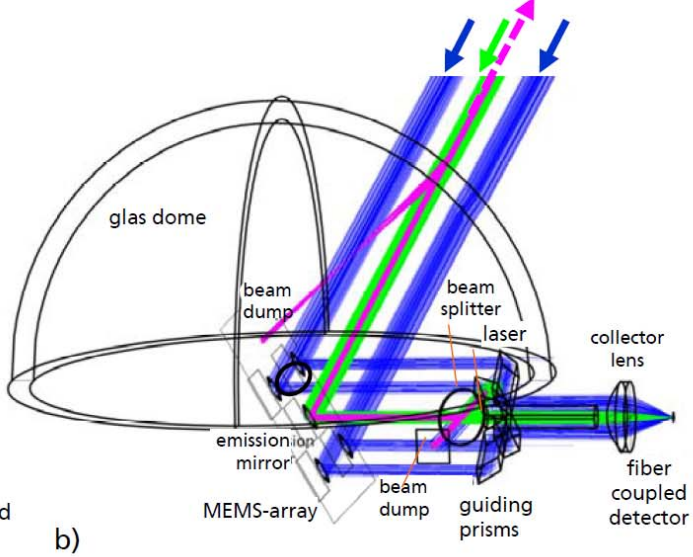
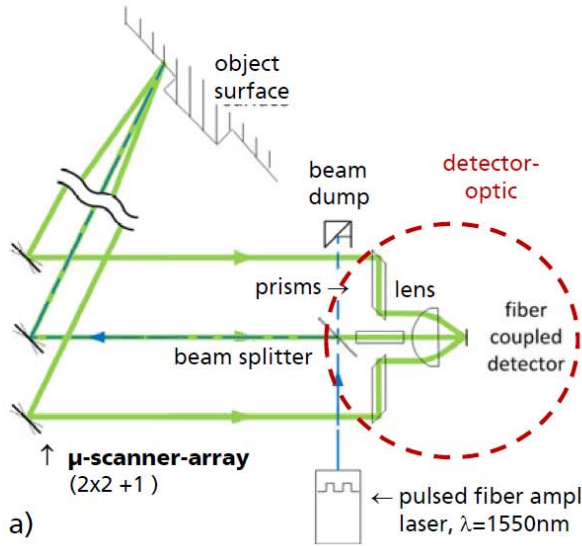
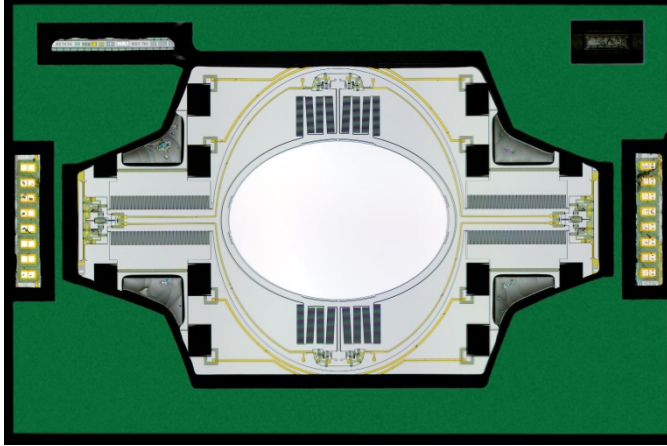
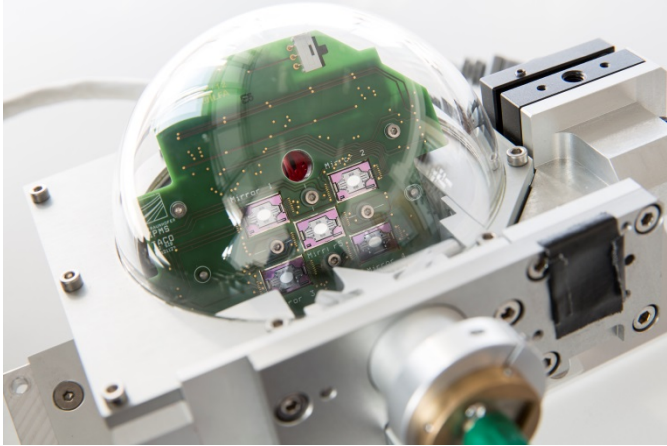
IMMS



DERMALOG

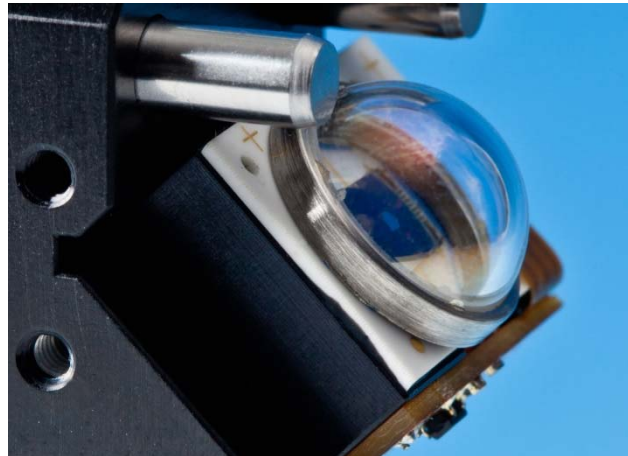


Application: 3D Camera

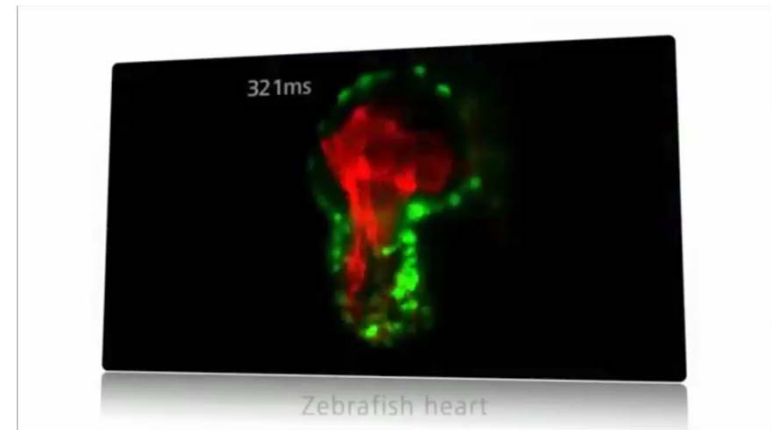
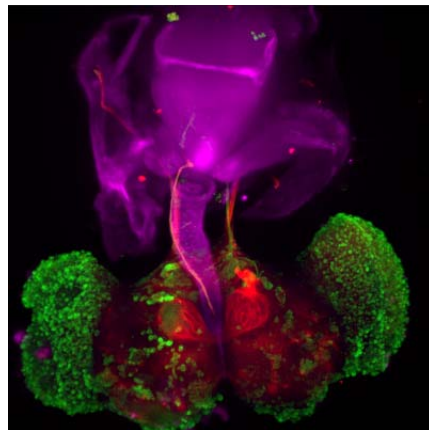


Application: Biomedical Imaging

ZEISS light sheet fluorescence microscope system Lightsheet Z.1



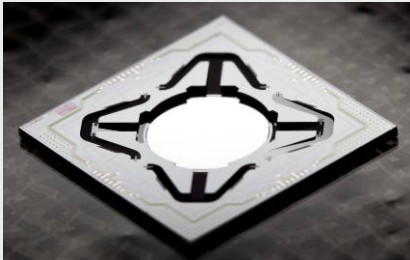
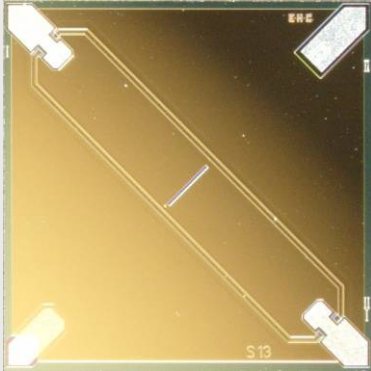
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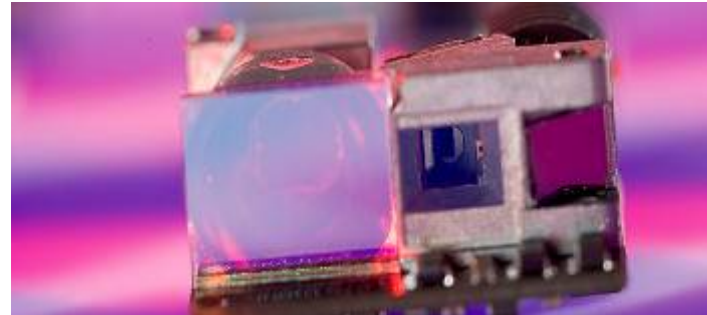
Technology Toolset at Fraunhofer IPMS



MEMS/ MOEMS		CMOS & „active“ Silicon
<p>Bulk MEMS</p> <ul style="list-style-type: none">■ 3- dim. Structures in Silicon■ Applications:<ul style="list-style-type: none">■ MEMS Scanner■ Pressure Sensor	<p>Surface MEMS</p> <ul style="list-style-type: none">■ Thin film surface MEMS■ MEMS on CMOS■ Applications:<ul style="list-style-type: none">■ Spatial Light Modulator■ CMUTs 	<ul style="list-style-type: none">■ High Voltage CMOS■ Photodiodes■ pH- Sensor 

PILOT / LOW-VOLUME FABRICATION

Barcode reading systems based on micro scanning mirrors

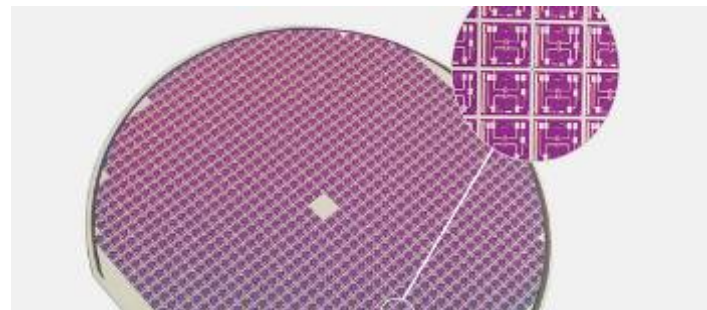


PIN-Diodes for high precision optical measurement and positioning



N.N.

Piezo resistive pressure sensors for automotive applications



THANK YOU FOR YOUR ATTENTION!

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